

## isc N-Channel MOSFET Transistor

**FCP290N80**

### • FEATURES

- With TO-220 packaging
- Low switching loss
- Ultra low gate charge
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

### • APPLICATIONS

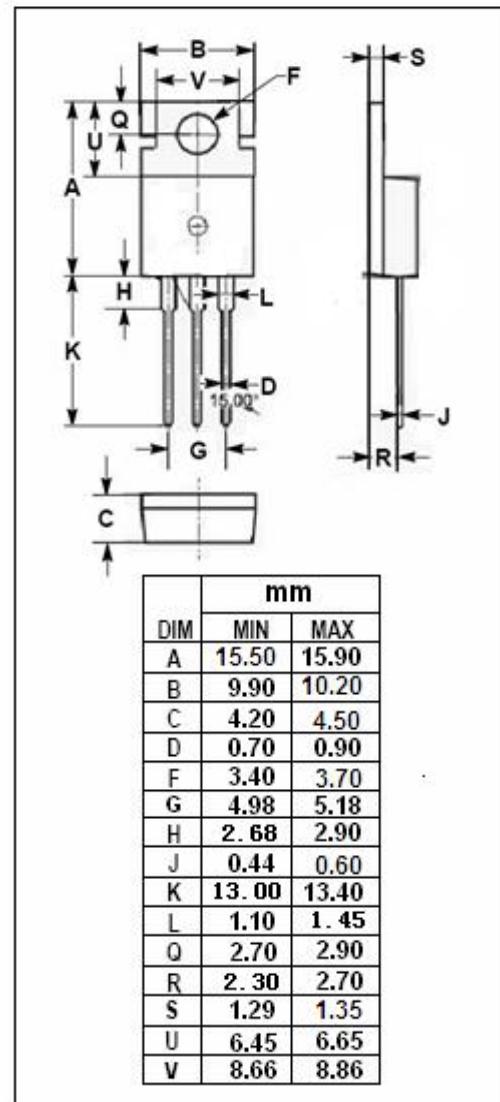
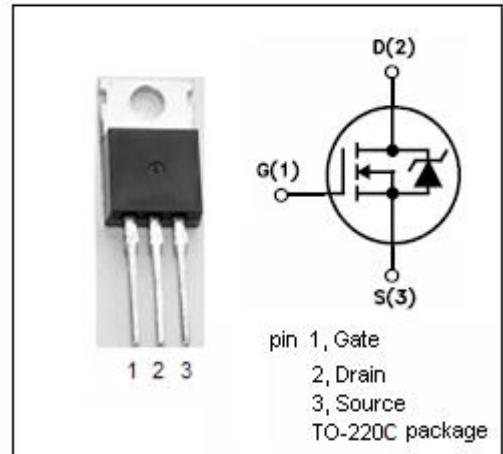
- Switching applications
- AC-DC converters
- LED lighting
- Uninterruptible power supply

### • ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	800	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous@ $T_c=25^\circ\text{C}$ $T_c=100^\circ\text{C}$	17 10.8	A
$I_{DM}$	Drain Current-Single Pulsed	42	A
$P_D$	Total Dissipation	212	W
$T_j$	Operating Junction Temperature	-55~150	°C
$T_{stg}$	Storage Temperature	-55~150	°C

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.59	°C/W
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	°C/W



**isc N-Channel MOSFET Transistor****FCP290N80****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D= 1\text{mA}$	800			V
$\text{V}_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\pm 20\text{V}; \text{I}_D=1.7\text{mA}$	2.5		4.5	V
$\text{R}_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D=8.5\text{A}$		245	290	$\text{m}\Omega$
$\text{I}_{\text{GSS}}$	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			$\pm 0.1$	$\mu\text{A}$
$\text{I}_{\text{DSS}}$	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= 800\text{V}; \text{V}_{\text{GS}}= 0\text{V}; \text{T}_j=25^\circ\text{C}$ $\text{V}_{\text{DS}}= 640\text{V}; \text{V}_{\text{GS}}= 0\text{V}; \text{T}_j=125^\circ\text{C}$			25 250	$\mu\text{A}$
$\text{V}_{\text{SDF}}$	Diode forward voltage	$\text{I}_{\text{SD}}=17\text{A}, \text{V}_{\text{GS}} = 0 \text{ V}$			1.2	V